

DESCRIPTION

5 kV/µs.

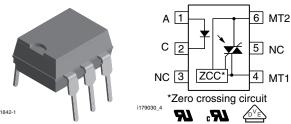
packaged in a DIP-6 package.

for bin H, and 3 mA for bin M.

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Vishay Semiconductors

Optocoupler, Phototriac Output, Zero Crossing, High dV/dt, Low Input Current



FEATURES

- High static dV/dt 5 kV/µs
- High input sensitivity I_{FT} = 1.6 mA, 2 mA, and
- 300 mA on-state current
- Zero voltage crossing detector
- 700 V and 800 V blocking voltage
- Isolation test voltage 5300 V_{RMS}
- Compliant to RoHS Directive 2011/65/EU

APPLICATIONS

- Solid-state relays
- · Industrial controls
- Office equipment
- Consumer appliances

AGENCY APPROVALS

- UL1577, file no. E52744 system code H or J, double protection
- cUL file no. E52744, equivalent to CSA bulletin 5A
- DIN EN 60747-5-2 (VDE 0884) available with option 1
- FIMKO

21842-1

The VO4157 and VO4158 consists of a GaAs IRLED

optically coupled to a photosensitive zero crossing TRIAC

High input sensitivity is achieved by using an emitter follower phototransistor and a cascaded SCR predriver

resulting in an LED trigger current of 1.6 mA for bin D, 2 mA

The new phototriac zero crossing family uses a proprietary dV/dt clamp resulting in a static dV/dt of greater than

The VO4157 and VO4158 isolates low-voltage logic from

120 V_{AC} , 240 V_{AC} , and 380 V_{AC} lines to control resistive,

inductive, or capacitive loads including motors, solenoids,

high current thyristors or TRIAC and relays.

ORDERING INFORMATION DIP-6 Option 6 ٧ 0 5 X X 0 Т TAPE PART NUMBER PACKAGE OPTION 10.16 mn 7.62 mn AND REEL Option 7 Option 8 **V_{DRM} 700 V_{DRM} 800 AGENCY CERTIFIED/PACKAGE** TRIGGER CURRENT, I_{FT} (mA) UL, cUL 1.6 2 3 1.6 2 3 VO4157D VO4157H VO4157M VO4158D VO4158H VO4158M DIP-6 DIP-6, 400 mil, option 6 VO4157D-X006 VO4157H-X006 VO4157M-X006 VO4158D-X006 VO4158H-X006 VO4158M-X006 SMD-6, option 7 VO4157D-X007T VO4157H-X007T VO4157M-X007T VO4158D-X007T VO4158H-X007T VO4158M-X007T VDE, UL, cUL 1.6 1.6 2 2 3 DIP-6 VO4157M-X001 DIP-6, 400 mil, option 6 VO4158M-X016 SMD-6, option 7 VO4157D-X017T VO4157H-X017T VO4157M-X017T VO4158H-X017T SMD-6, option 8 VO4158M-X018T



ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT		
INPUT							
Reverse voltage			V_{R}	6	V		
Forward current			I _F	60	mA		
Surge current			I _{FSM}	2.5	Α		
Derate from 25 °C				1.33	mW/°C		
OUTPUT							
Peak off-state voltage		VO4157D/H/M	V_{DRM}	700	V		
Peak on-state voltage		VO4158D/H/M	V_{DRM}	800	V		
RMS on-state current			I _{TM}	300	mA		
Derate from 25 °C				6.6	mW/°C		
COUPLER							
Isolation test voltage (between emitter and detector, climate per DIN 500414, part 2, Nov. 74)	t = 1 min		V_{ISO}	5300	V_{RMS}		
Storage temperature range			T _{stg}	- 55 to + 150	°C		
Ambient temperature range			T _{amb}	- 55 to + 100	°C		
Soldering temperature	max. ≤ 10 s dip soldering ≥ 0.5 mm from case bottom		T _{sld}	260	°C		

Note

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.
 This phototriac should not be used to drive a load directly. It is intended to be a trigger device only.

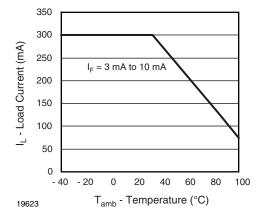


Fig. 1 - Recommended Operating Condition



THERMAL CHARACTERISTICS			
PARAMETER	SYMBOL	VALUE	UNIT
LED power dissipation	P _{diss}	100	mW
Output power dissipation	P _{diss}	500	mW
Total power dissipation	P _{tot}	600	mW
Maximum LED junction temperature	T _{jmax.}	125	°C
Maximum output die junction temperature	T _{jmax.}	125	°C
Thermal resistance, junction emitter to board	θ_{JEB}	150	°C/W
Thermal resistance, junction emitter to case	θ_{JEC}	139	°C/W
Thermal resistance, junction detector to board	θ_{JDB}	78	°C/W
Thermal resistance, junction detector to case	θ_{JDC}	103	°C/W
Thermal resistance, junction emitter to junction detector	θ_{JED}	496	°C/W
Thermal resistance, case to ambient	θ_{CA}	3563	°C/W

Note

The thermal characteristics table above were measured at 25 °C and the thermal model is represented in the thermal network below. Each
resistance value given in this model can be used to calculate the temperatures at each node for a given operating condition. The thermal
resistance from board to ambient will be dependent on the type of PCB, layout and thickness of copper traces. For a detailed explanation
of the thermal model, please reference Vishay's Thermal Characteristics of Optocouplers application note.

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT							
Forward voltage	I _F = 10 mA		V _F		1.2	1.4	V
Reverse current	V _R = 6 V		I _R		0.1	10	μΑ
Input capacitance	V _F = 0 V, f = 1 MHz		C _I		25		pF
OUTPUT							
Repetitive peak off-state voltage	I _{DRM} = 100 μA	VO4157D/H/M	V_{DRM}	700			V
		VO4158D/H/M	V_{DRM}	800			V
Off-state current	$V_D = V_{DRM, I_F} = 0$		I _{DRM}			100	μΑ
On-state voltage	$I_T = 300 \text{ mA}$		V_{TM}			3	V
On-state current	PF = 1, V _{T(RMS)} = 1.7 V		I _{TM}			300	mA
Off-state current in inhibit state	$I_F = 2 \text{ mA}, V_{DRM}$		I _{DINH}			200	μΑ
Holding current			I _H			500	μΑ
Zero cross inhibit voltage	I_F = rated I_{FT}		V _{IH}			20	V
Critical rate of rise of off-state voltage	V _D = 0.67 V _{DRM} , T _J = 25 °C		dV/dt _{cr}	5000			V/µs
COUPLER							
LED trigger current, current required to latch output	V _D = 3 V	VO4157D	I _{FT}			1.6	mA
		VO4157H	I _{FT}			2	mA
		VO4157M	I _{FT}			3	mA
		VO4158D	I _{FT}			1.6	mA
		VO4158H	I _{FT}			2	mA
		VO4158M	I _{FT}			3	mA
Common mode coupling capacitance			C _{CM}		0.01		pF
Capacitance (input to output)	f = 1 MHz, V _{IO} = 0 V		C _{IO}		0.8		pF

Note

Minimum and maximum values were tested requierements. Typical values are characteristics of the device and are the result of engineering
evaluations. Typical values are for information only and are not part of the testing requirements.



SAFETY AND INSULATION RATINGS								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Climatic classification (according to IEC68 part 1)				55/100/21				
Pollution degree (DIN VDE 0109)				2				
Comparative tracking index per DIN IEC112/VDE 0303 part 1, group IIIa per DIN VDE 6110 175 399			175		399			
V _{IOTM}		V _{IOTM}	8000			V		
V _{IORM}		V _{IORM}	890			V		
P _{SO}		P _{SO}			500	mW		
I _{SI}		I _{SI}			250	mA		
T_{SI}		T _{SI}			175	°C		
Creepage distance			7			mm		

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

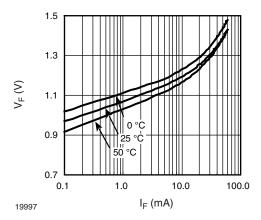


Fig. 2 - Diode Forward Voltage vs. Forward Current

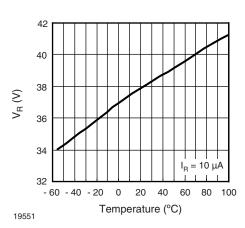


Fig. 3 - Diode Reverse Voltage vs. Temperature

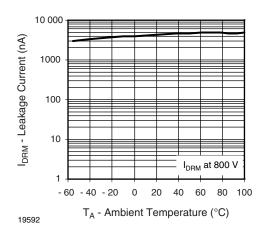


Fig. 4 - Leakage Current vs. Ambient Temperature

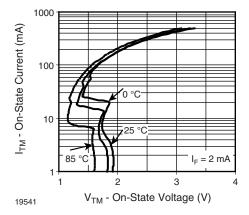


Fig. 5 - On State Current vs. On State Voltage

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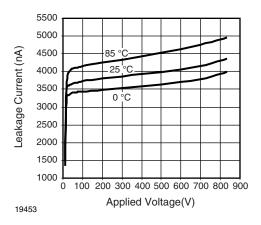


Fig. 6 - Output Off Current (Leakage) vs. Voltage

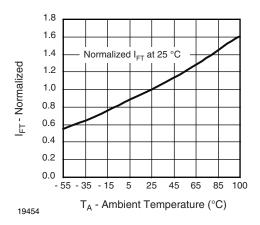


Fig. 7 - Normalized Trigger Input Current vs. Temperature

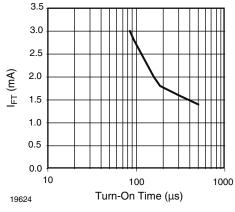


Fig. 8 - Trigger Current vs. Turn-On Time

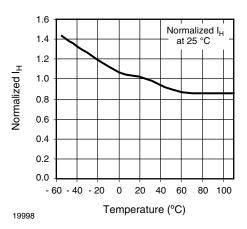


Fig. 9 - Normalized Holding Current vs. Temperature

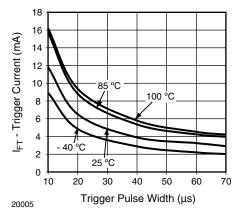


Fig. 10 - I_{FT} vs. LED Pulse Width

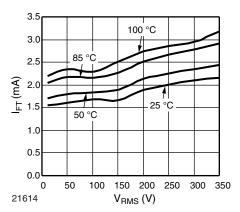


Fig. 11 - I_{FT} vs. V_{RMS} and Temperature



R1 360 Control 220/240 VAC 1009-1 Nutral

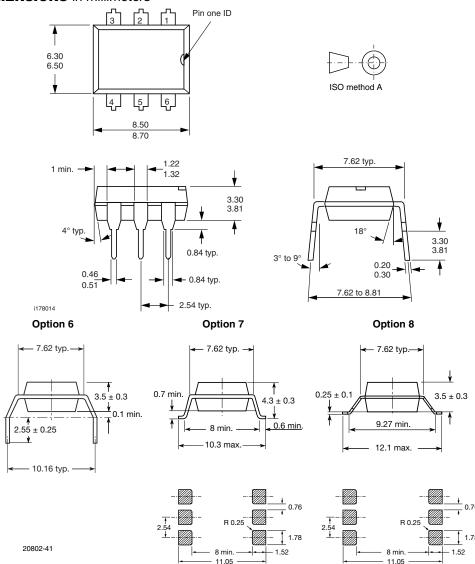
Fig. 12 - Basic Power Triac Driver Circuit

POWER FACTOR CONSIDERATIONS

As a zero voltage crossing optotriac, the commutating dV/dt spikes can inhibit one half of the TRIAC from turning on. If the spike potential exceeds the inhibit voltage of the zero-cross detection circuit, half of the TRIAC will be held-off and not turn-on. This hold-off condition can be eliminated by using a capacitor or RC snubber placed directly across the power triac as shown in fig. 11. Note that the value of the capacitor increases as a function of the load current.

The hold-off condition also can be eliminated by providing a higher level of LED drive current. The higher LED drive provides a larger photocurrent which causes the phototransistor to turn-on before the commutating spike has activated the zero-cross detection circuit. For example, if a device requires 1.5 mA for a resistive load, then 2.7 mA (1.8 times) may be required to control an inductive load whose power factor is less than 0.3.

PACKAGE DIMENSIONS in millimeters





PACKAGE MARKING (example)



Notes

• VDE logo is only marked on option 1 parts. Tape and reel suffix (T) is not part of the package marking.



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